

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(ON)}$ Max | I_D Max $T_A = 25^\circ\text{C}$ |
|---------------|--|---------------------------------------|
| 20V | 0.99 Ω @ $V_{GS} = 4.5\text{V}$ | 450mA |
| | 1.2 Ω @ $V_{GS} = 2.5\text{V}$ | 400mA |
| | 1.8 Ω @ $V_{GS} = 1.8\text{V}$ | 330mA |
| | 2.4 Ω @ $V_{GS} = 1.5\text{V}$ | 300mA |

Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

Features

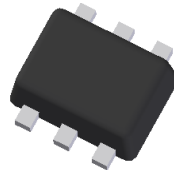
- Dual N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package 1mm x 1mm
- Low Package Profile, 0.45mm Maximum Package Height
- ESD Protected Gate
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **An Automotive-Compliant Part is Available Under Separate Datasheet ([DMN2990UDJQ](#))**

Mechanical Data

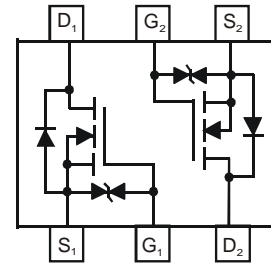
- Case: SOT963
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish — Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 E^3
- Weight: 0.027 grams (Approximate)



SOT963



Top View



Top View
Schematic and Transistor Diagram

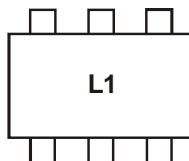
Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|--------|-----------------|
| DMN2990UDJ-7 | SOT963 | 10K/Tape & Reel |
| DMN2990UDJ-7A | SOT963 | 10K/Tape & Reel |

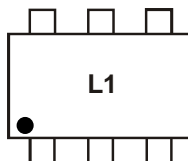
- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information (Note 5 & 6)

DMN2990UDJ-7 (Note 5)



DMN2990UDJ-7A (Note 6)



L1 = Product Type Marking Code

- Notes:
5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
 6. Part number with suffix 7A designates devices marked with a Pin 1 indicator. There is no other difference between both devices.

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|--|--------------|------------------------|------------------|-------|------|
| Drain-Source Voltage | | | V _{DSS} | 20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±8 | V |
| Continuous Drain Current (Note 7) V _{GS} = 4.5V | Steady State | T _A = +25°C | I _D | 450 | mA |
| | | T _A = +70°C | | 350 | |
| Continuous Drain Current (Note 7) V _{GS} = 1.8V | Steady State | T _A = +25°C | I _D | 330 | mA |
| | | T _A = +70°C | | 220 | |
| Pulsed Drain Current (Note 8) | | | I _{DM} | 800 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 7) | P _D | 350 | mW |
| Thermal Resistance, Junction to Ambient | R _{θJA} | 360 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---------------------|-----|------|------|------|---|
| OFF CHARACTERISTICS (Note 9) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | - | - | V | V _{GS} = 0V, I _D = 250μA |
| Zero Gate Voltage Drain Current @T _C = +25°C | I _{DSS} | - | - | 50 | nA | V _{DS} = 5V, V _{GS} = 0V |
| | | - | - | 100 | | V _{DS} = 16V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | - | - | ±100 | nA | V _{GS} = ±5V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 9) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.4 | - | 1.0 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | - | 0.60 | 0.99 | Ω | V _{GS} = 4.5V, I _D = 100mA |
| | | - | 0.75 | 1.2 | | V _{GS} = 2.5V, I _D = 50mA |
| | | - | 0.90 | 1.8 | | V _{GS} = 1.8V, I _D = 20mA |
| | | - | 1.2 | 2.4 | | V _{GS} = 1.5V, I _D = 10mA |
| | | - | 2.0 | - | | V _{GS} = 1.2V, I _D = 1mA |
| Forward Transfer Admittance | Y _{fs} | 180 | - | - | ms | V _{DS} = 10V, I _D = 400mA |
| Diode Forward Voltage (Note 8) | V _{SD} | - | 0.6 | 1.0 | V | V _{GS} = 0V, I _S = 150mA |
| DYNAMIC CHARACTERISTICS (Note 10) | | | | | | |
| Input Capacitance | C _{iss} | - | 27.6 | - | pF | V _{DS} = 16V, V _{GS} = 0V, f = 1.0MHz |
| Output Capacitance | C _{oss} | - | 4.0 | - | pF | |
| Reverse Transfer Capacitance | C _{rss} | - | 2.8 | - | pF | |
| Total Gate Charge | Q _g | - | 0.5 | - | nC | V _{GS} = 4.5V, V _{DS} = 10V, I _D = 250mA |
| Gate-Source Charge | Q _{gs} | - | 0.07 | - | nC | |
| Gate-Drain Charge | Q _{gd} | - | 0.07 | - | nC | |
| Turn-On Delay Time | t _{D(ON)} | - | 4.0 | - | ns | V _{DD} = 10V, V _{GS} = 4.5V, R _L = 47Ω, R _g = 10Ω, I _D = 200mA |
| Turn-On Rise Time | t _R | - | 3.3 | - | ns | |
| Turn-Off Delay Time | t _{D(OFF)} | - | 19.0 | - | ns | |
| Turn-Off Fall Time | t _F | - | 6.4 | - | ns | |

- Notes:
7. Device mounted on FR-4 PCB, with minimum recommended pad layout.
 8. Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.
 9. Short duration pulse test used to minimize self-heating effect.
 10. Guaranteed by design. Not subject to product testing.

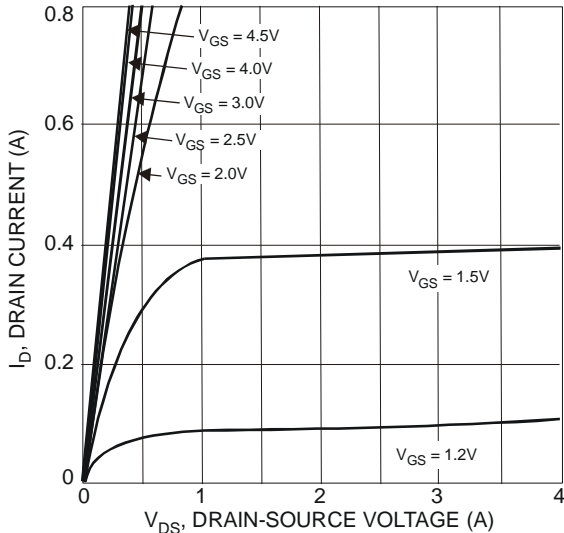


Fig. 1 Typical Output Characteristics

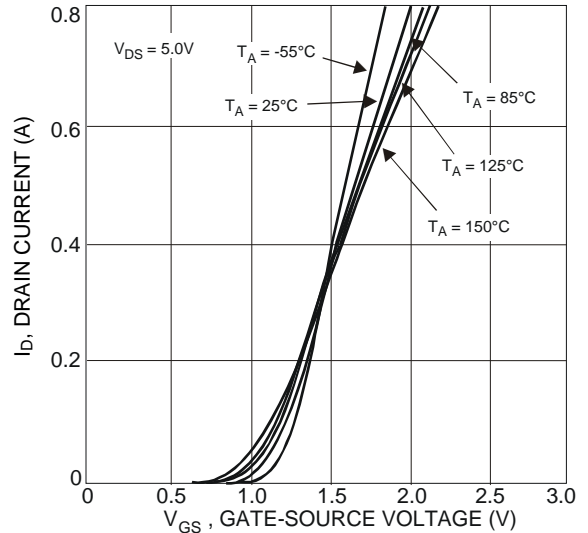


Fig. 2 Typical Transfer Characteristics

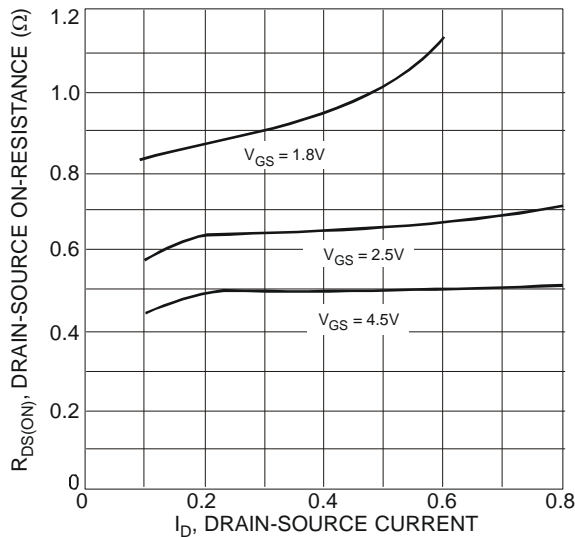


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

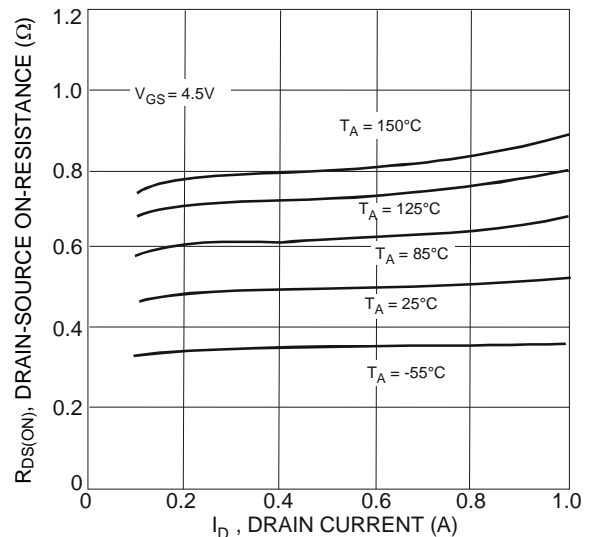


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

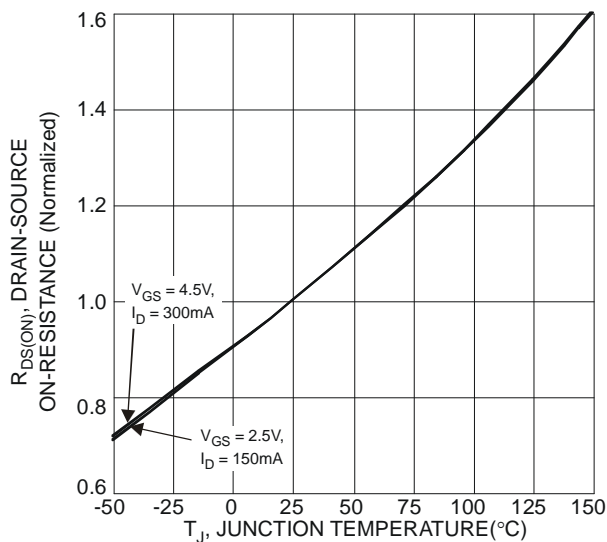


Fig. 5 On-Resistance Variation with Temperature

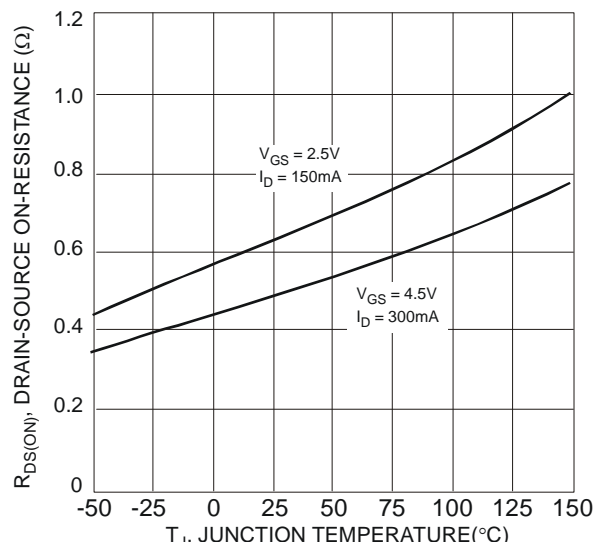


Fig. 6 On-Resistance Variation with Temperature

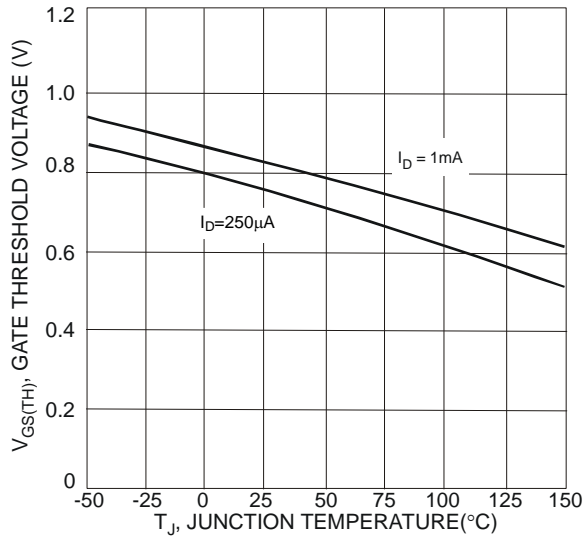


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

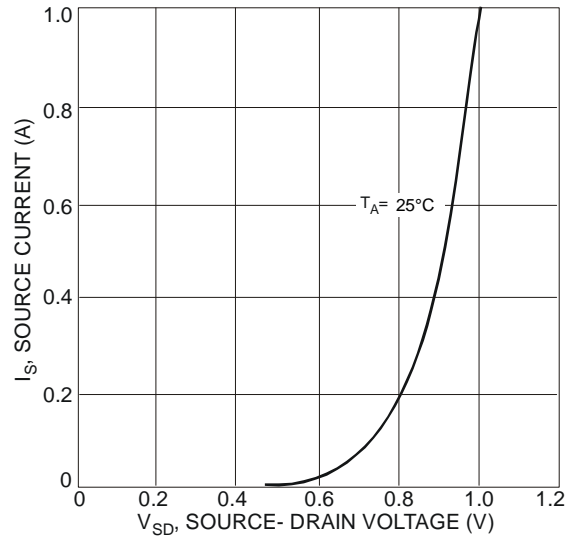


Fig. 8 Diodes Forward Voltage vs. Current

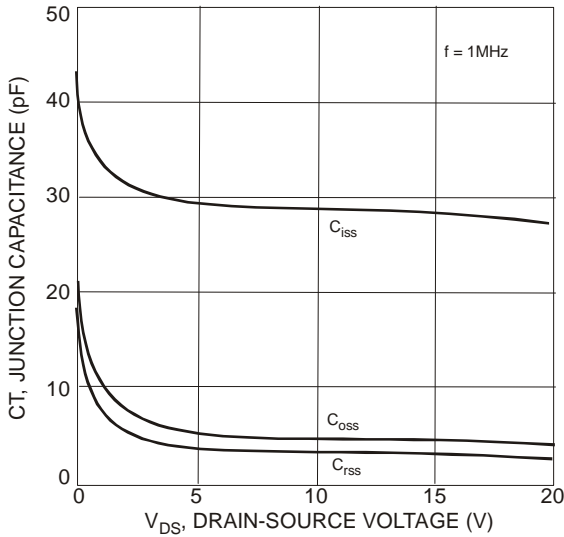


Fig. 9 Typical Junction Capacitance

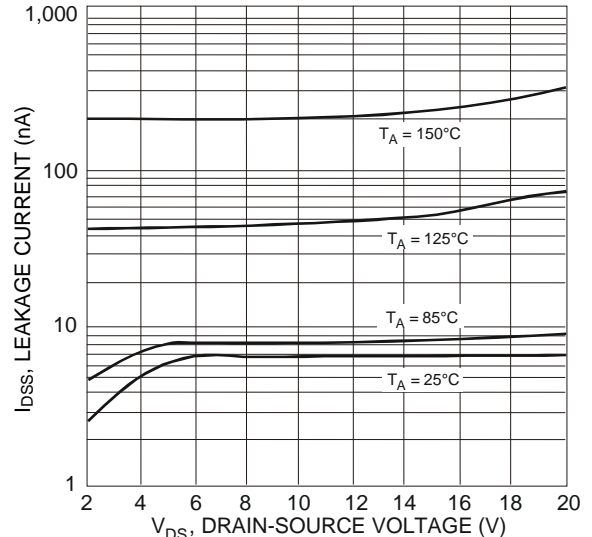


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

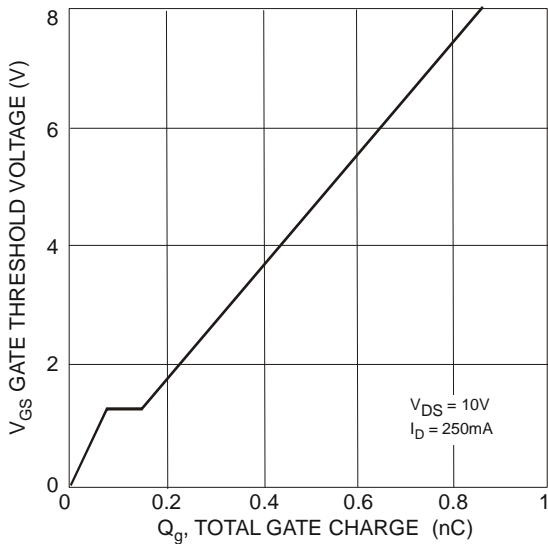


Fig. 11 Gate Charge

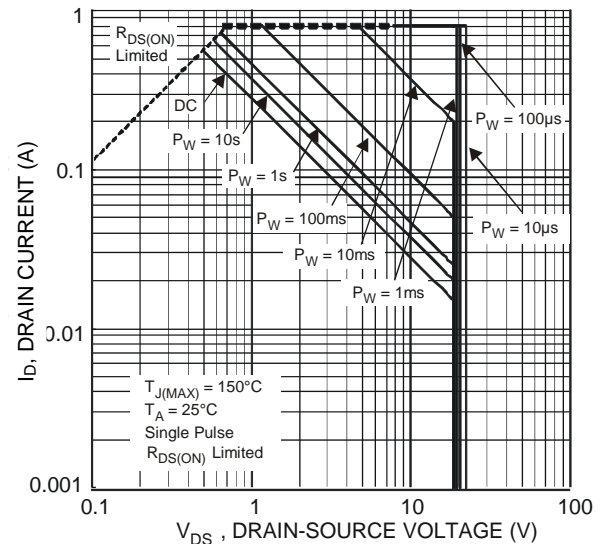
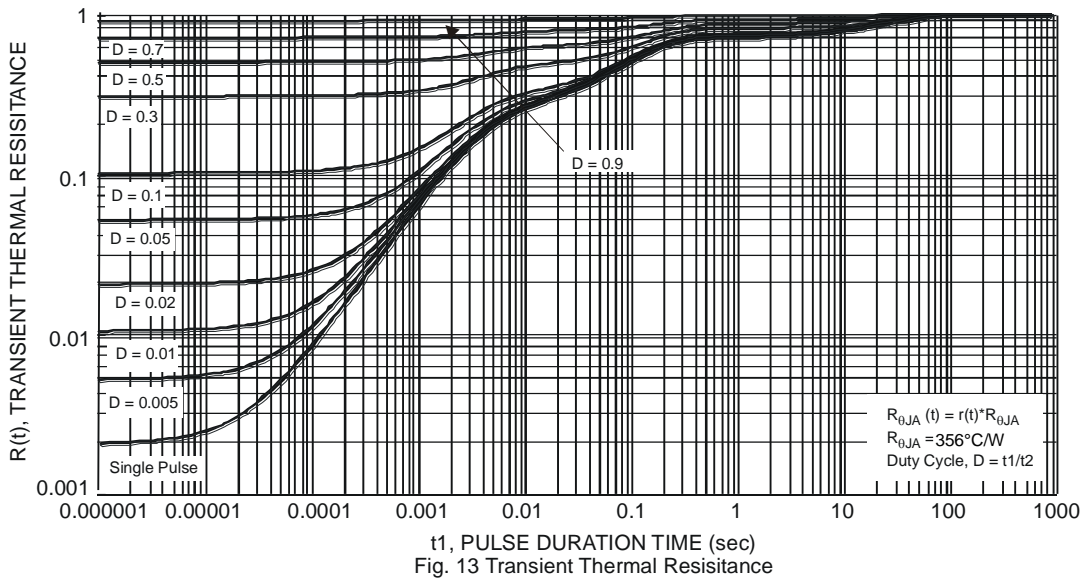


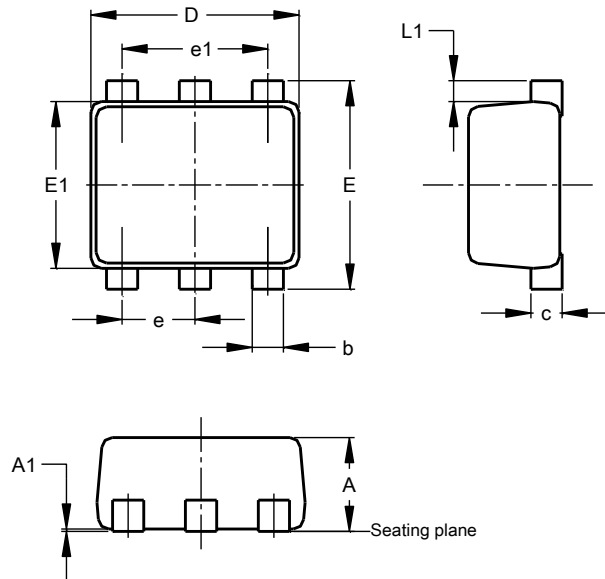
Fig. 12 SOA, Safe Operation Area



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT963

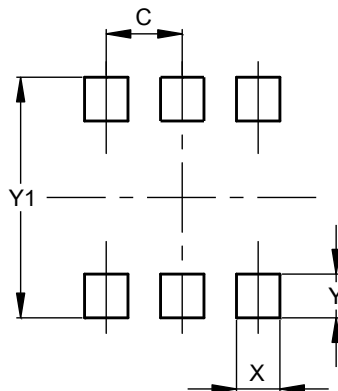


| SOT963 | | | |
|-----------------------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| A | 0.40 | 0.50 | 0.45 |
| A1 | 0.00 | 0.05 | -- |
| b | 0.10 | 0.20 | 0.15 |
| c | 0.120 | 0.180 | 0.150 |
| D | 0.95 | 1.05 | 1.00 |
| E | 0.95 | 1.05 | 1.00 |
| E1 | 0.75 | 0.85 | 0.80 |
| e | -- | -- | 0.35 |
| e1 | -- | -- | 0.70 |
| L1 | 0.05 | 0.15 | 0.10 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT963



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.350 |
| X | 0.200 |
| Y | 0.200 |
| Y1 | 1.100 |

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